

---

## MR27V401D

---

524,288-Word x 8-Bit

Production Programmed Read Only Memory (P2ROM)

---

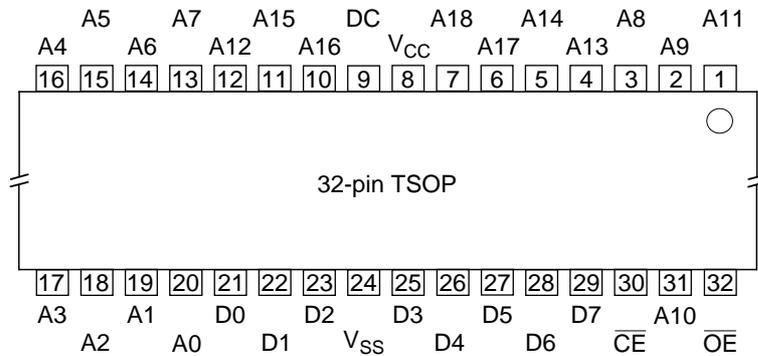
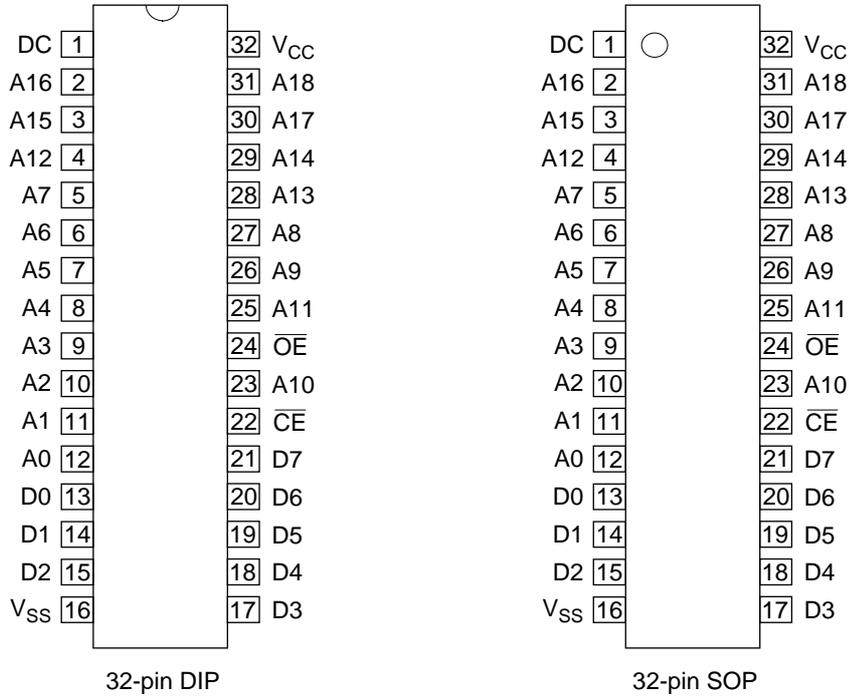
### DESCRIPTION

The MR27V401D is a 4Mbit Production Programmed Read-Only Memory (P2ROM) organized as 524,288word x 8bit. The MR27V401D operates on a single +3V-3.3V power supply and is TTL compatible. Since the MR27V401D operates asynchronously, external clocks are not required, making this device easy-to-use. The MR27V401D is suitable as large-capacity fixed memory for microcomputers and data terminals. It is manufactured using a CMOS double silicon gate technology and is offered in 32-pin DIP, 32-pin SOP or 32-pin TSOP packages.

### FEATURES

- 524,288 word x 8bit
- Single +3V-3.3V power supply
- Access time                   80ns access time (Vcc=+3V)  
  70ns access time (Vcc=+3.3V)
- Input / Output TTL compatible
- Three-state output
- Packages
  - 32-pin plastic DIP (DIP32-P-600-2.54)                   (Product name : MR27V401D-xxRA)
  - 32-pin plastic SOP (SOP32-P-525-1.27-K)               (Product name : MR27V401D-xxMA)
  - 32-pin plastic TSOP (TSOP I 32-P-814-0.50-K) (Product name : MR27V401D-xxTA)

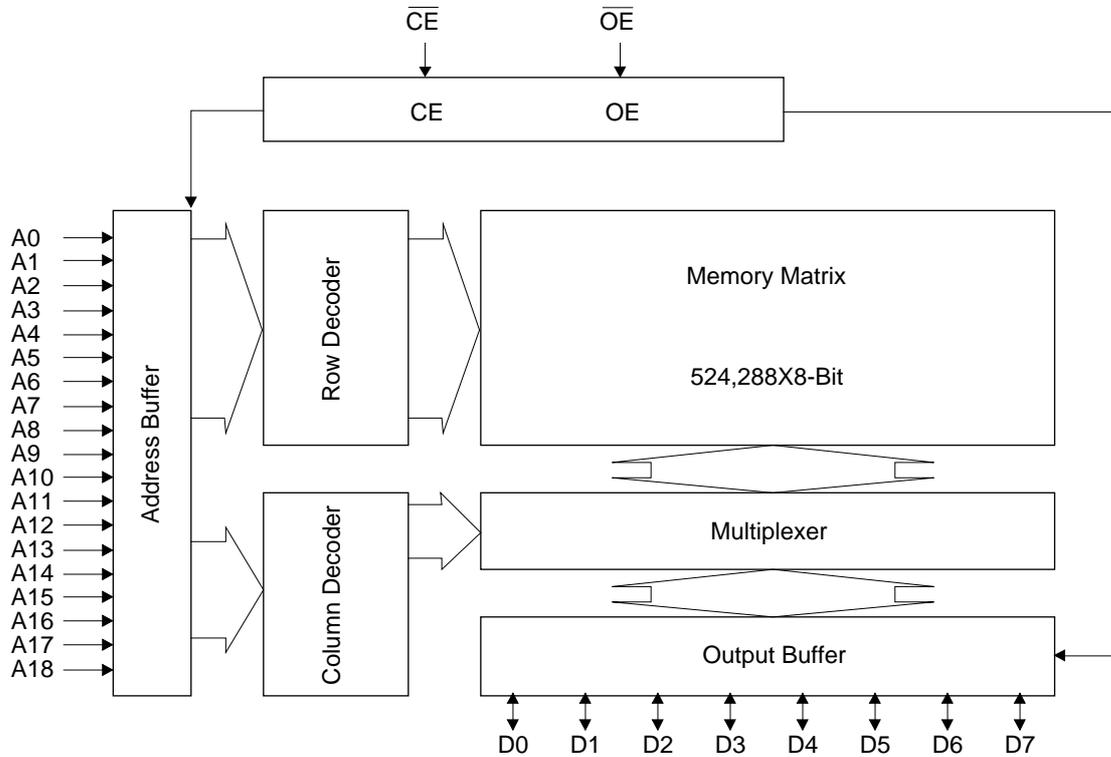
## PIN CONFIGURATION (TOP VIEW)



PIN NAMES	FUNCTIONS
A0 - A18	Address input
D0 - D7	Data output
CE	Chip enable
OE	Output enable
V <sub>CC</sub>	Power supply voltage
V <sub>SS</sub>	GND
DC	Don't care *

\* : Logical input level is ignored , however the pin is connected to internal circuit.

## BLOCK DIAGRAM



## FUNCTION TABLE

MODE	$\overline{CE}$	$\overline{OE}$	DC	$V_{CC}$	D0 - D7
READ	L	L	**	3.0V to 3.3V	$D_{OUT}$
OUTPUT DISABLE	L	H			Hi-Z
STAND-BY	H	*			Hi-Z

\* : Don't Care (H or L)

\*\* : Don't Care (H or L or Open)

**ABSOLUTE MAXIMUM RATINGS**

Parameter	Symbol	Condition	Value	Unit
Operating temperature under bias	$T_{opr}$	-	0 to 70	°C
Storage temperature	$T_{stg}$		-55 to 125	°C
Input voltage	$V_I$	relative to $V_{SS}$	-0.5 to $V_{CC} + 0.5$	V
Output voltage	$V_O$		-0.5 to $V_{CC} + 0.5$	V
Power supply voltage	$V_{CC}$		-0.5 to 5	V
Power dissipation per package	$P_D$	-	1.0	W

**RECOMMENDED OPERATING CONDITIONS**

(Ta=0 to 70°C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
$V_{CC}$ power supply voltage	$V_{CC}$	$V_{CC}=2.7V - 3.6V$	2.7	-	3.6	V
Input "H" level	$V_{IH}$		2.2	-	$V_{CC}+0.5^*$	V
Input "L" level	$V_{IL}$		-0.5**	-	0.6	V

Voltage is relative to  $V_{SS}$ \* :  $V_{CC}+1.5V$  (Max.) when pulse width of overshoot is less than 10nS.

\*\* : -1.5V (Min.) when pulse width of undershoot is less than 10nS.

**ELECTRICAL CHARACTERISTICS (Read operation)****DC Characteristics 1**(V<sub>CC</sub>=3V±0.3V, Ta=0 to 70°C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Input leakage current	I <sub>LI</sub>	V <sub>I</sub> =0 to V <sub>CC</sub>	-	-	10	μA
Output leakage current	I <sub>LO</sub>	V <sub>O</sub> =0 to V <sub>CC</sub>	-	-	10	μA
V <sub>CC</sub> power supply current (Standby)	I <sub>CCSC</sub>	$\overline{CE}=V_{CC}$	-	-	50	μA
	I <sub>CCST</sub>	$\overline{CE}=V_{IH}$	-	-	1	mA
V <sub>CC</sub> power supply current (Read)	I <sub>CCA</sub>	$\overline{CE}=V_{IL}$ , $\overline{OE}=V_{IH}$ tc=80ns	-	-	20	mA
Input "H" level	V <sub>IH</sub>	-	2.2	-	V <sub>CC</sub> +0.5*	V
Input "L" level	V <sub>IL</sub>	-	-0.5**	-	0.6	V
Output "H" level	V <sub>OH</sub>	I <sub>OH</sub> =-400μA	2.4	-	-	V
Output "L" level	V <sub>OL</sub>	I <sub>OL</sub> =2.1mA	-	-	0.4	V

Voltage is relative to V<sub>SS</sub>\* : V<sub>CC</sub>+1.5V (Max.) when pulse width of overshoot is less than 10nS.

\*\* : -1.5V (Min.) when pulse width of undershoot is less than 10nS.

**DC Characteristics 2**(V<sub>CC</sub>=3.3V±0.3V, Ta=0 to 70°C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Input leakage current	I <sub>LI</sub>	V <sub>I</sub> =0 to V <sub>CC</sub>	-	-	10	μA
Output leakage current	I <sub>LO</sub>	V <sub>O</sub> =0 to V <sub>CC</sub>	-	-	10	μA
V <sub>CC</sub> power supply current (Standby)	I <sub>CCSC</sub>	$\overline{CE}=V_{CC}$	-	-	50	μA
	I <sub>CCST</sub>	$\overline{CE}=V_{IH}$	-	-	1	mA
V <sub>CC</sub> power supply current (Read)	I <sub>CCA</sub>	$\overline{CE}=V_{IL}$ , $\overline{OE}=V_{IH}$ tc=70ns	-	-	25	mA
Input "H" level	V <sub>IH</sub>	-	2.2	-	V <sub>CC</sub> +0.5*	V
Input "L" level	V <sub>IL</sub>	-	-0.5**	-	0.6	V
Output "H" level	V <sub>OH</sub>	I <sub>OH</sub> =-400μA	2.4	-	-	V
Output "L" level	V <sub>OL</sub>	I <sub>OL</sub> =2.1mA	-	-	0.4	V

Voltage is relative to V<sub>SS</sub>\* : V<sub>CC</sub>+1.5V (Max.) when pulse width of overshoot is less than 10nS.

\*\* : -1.5V (Min.) when pulse width of undershoot is less than 10nS.

**AC Characteristics 1** $(V_{CC}=3V\pm 0.3V, T_a=0 \text{ to } 70^\circ\text{C})$ 

Parameter	Symbol	Condition	Min.	Max.	Unit
Address cycle time	$T_C$	-	80	-	ns
Address access time	$T_{ACC}$	$\overline{CE}=\overline{OE}=V_{IL}$	-	80	ns
$\overline{CE}$ access time	$T_{CE}$	$\overline{OE}=V_{IL}$	-	80	ns
$\overline{OE}$ access time	$T_{OE}$	$\overline{CE}=V_{IL}$	-	40	ns
Output disable time	$T_{CHZ}$	$\overline{OE}=V_{IL}$	0	30	ns
	$T_{OHZ}$	$\overline{CE}=V_{IL}$	0	25	ns
Output hold time	$T_{OH}$	$\overline{CE}=\overline{OE}=V_{IL}$	0	-	ns

## Measurement conditions

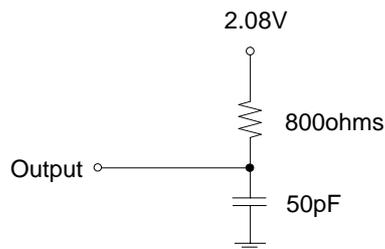
Input signal level	-----	0V/3V
Input timing reference level	-----	0.8V/2.0V
Output load	-----	50pF
Output timing reference level	-----	0.8V/2.0V

**AC Characteristics 2** $(V_{CC}=3.3V\pm 0.3V, T_a=0 \text{ to } 70^\circ\text{C})$ 

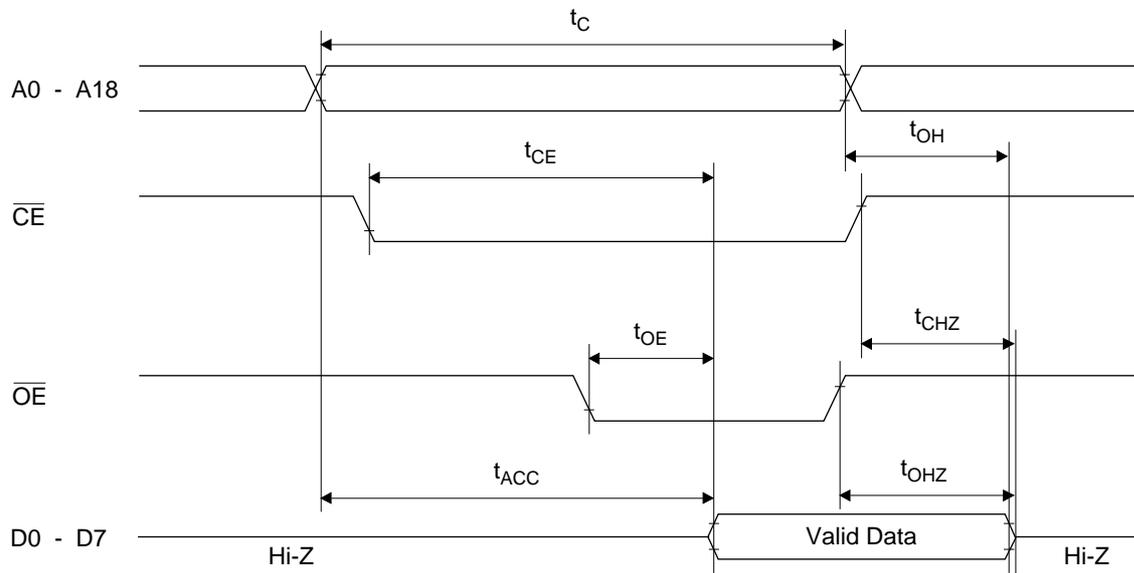
Parameter	Symbol	Condition	Min.	Max.	Unit
Address cycle time	$T_C$	-	70	-	ns
Address access time	$T_{ACC}$	$\overline{CE}=\overline{OE}=V_{IL}$	-	70	ns
$\overline{CE}$ access time	$T_{CE}$	$\overline{OE}=V_{IL}$	-	70	ns
$\overline{OE}$ access time	$T_{OE}$	$\overline{CE}=V_{IL}$	-	35	ns
Output disable time	$T_{CHZ}$	$\overline{OE}=V_{IL}$	0	30	ns
	$T_{OHZ}$	$\overline{CE}=V_{IL}$	0	25	ns
Output hold time	$T_{OH}$	$\overline{CE}=\overline{OE}=V_{IL}$	0	-	ns

## Measurement conditions

Input signal level	-----	0V/3V
Input timing reference level	-----	0.8V/2.0V
Output load	-----	50pF
Output timing reference level	-----	0.8V/2.0V



## TIMING CHART (READ CYCLE)



## PIN Capacitance

(V<sub>CC</sub>=3.3V, T<sub>a</sub>=25°C, f=1MHz)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Input	C <sub>IN</sub>	V <sub>I</sub> =0V	-	-	8 (10)	pF
Output	C <sub>OUT</sub>	V <sub>O</sub> =0V	-	-	10 (12)	

( ) : DIP only